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Sub-micrometer waveguide for nano-optics.

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Summary: With the recent progress within the field of processing nano structures, such as silicon nano-wires, carbon nano-tubes and silicon crystal waveguides, there is an increasing interest in coupling light into such structures both for characterization of optical properties and new optical components [1]. Examples include measurements on the Raman spectrum of carbon nano-tubes, and an optical switch based on reflection of light against a nano sphere.

In this work we propose the use of a sub-micrometer planar waveguide for probing the reflection of light against a nano structure. The planar waveguide is based on a silicon nitride core layer, surrounded by a silica cladding region. This material system provides a high index difference between the core and cladding region and hence a strong confinement of the electrical field. In our design we utilize this waveuide to couple light into a nano-structure. Recently we have experimentally achieved low propagation loss, 0.7 dB/cm, in such high index waveguides.

The nano structures that we consider are either carbon nano tubes or silicon nano wires. The diameter of these structures is in the order of tens to hundreds of nanometers. To achieve maximum coupling with the light we have designed a probe as illustrated in Fig 1. The waveguide is theoretically analyzed using a boundary integral equation method [2]. In this method the mode of the waveguide is assumed to be well known at cross sections far away from the tip $z \rightarrow -\infty$, and the electric field in the tip region is found by applying Green's theorem to the regions around the tip and approaching the boundary from the cladding and core region. With the refractive index profile determined by our material, i.e. n=1.5 for the SiO₂ cladding and n=2.1 for the SRN cladding, single mode operation is achieved for a cross-section 0.6 μ m times 0.6 μ m, when the considered wavelength is 1550 nm.

The essential design parameters of the probe are the angle of the tip and the radius of the circle defining the central boundary of the probe see Fig.1. The power reflection coefficient, defined as the power reflected relative to the power launched into the waveguide, is illustrated in Fig. 2 as a function of the design parameters. As opposed to a standard waveguide, based on a germanium doped silica core and a silica cladding region with a refractive index difference of only 0.02, the preferred tip in the high index waveguide is a long taper, i.e. low taper angle and a small circle radius, r'=25 nm in Fig. 1. In addition to the optimized design of the waveguide probe we will also report on the reflection versus various reflectors placed in the vicinity of the probe. The reflectors have different size and material properties.



Fig. 1, Definition of geometrical waveguide parameters.



Fig. 2, Reflection versus taper angle for three different circle radii, r' in Fig. 1, the upper trace r'=165 nm the middle trace r'=8 nm and the lower trace r'=25 nm

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